



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
20V	0.99Ω @ V _{GS} = 4.5V	520mA
	1.2Ω @ V _{GS} = 2.5V	470mA
	1.8Ω @ V _{GS} = 1.8V	385mA
	2.4Ω @ V _{GS} = 1.5V	330mA

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

- General Purpose Interfacing Switch
- **Power Management Functions**
- **DC-DC Converters**
- Analog Switch

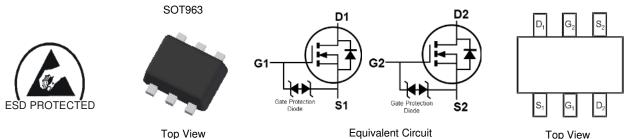
Notes:

Features

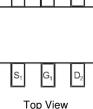
- **Dual N-Channel MOSFET**
- Low On-Resistance
- Very Low Gate Threshold Voltage, 1.0V Max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 1mm x 1mm
- Low Package Profile, 0.45mm Maximum Package Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: SOT963 •
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.027 grams (Approximate)



Equivalent Circuit



Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2991UDJ-7	SOT963	10K/Tape & Reel
DMN2991UDJ-7A	SOT963	10K/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

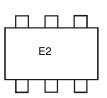
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

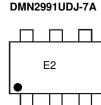
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information (Notes 5 & 6)

DMN2991UDJ-7





E2 = Product Type Marking Code

5. Package is non-polarized. Parts may be on reel in orientation illustrated, 180° rotated, or mixed (both ways). Notes:

6. Part number with suffix 7A designates devices marked with a Pin 1 indicator. There is no other difference between both devices.

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 7) V_{GS} = 4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	520 415	mA
Continuous Drain Current (Note 7) V_{GS} = 1.8V	Steady State	T _A = +25°C T _A = +70°C	ID	385 308	mA
Pulsed Drain Current (Note 8)			I _{DM}	1.4	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 7)	PD	0.4	W
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	312	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	20	—	—	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current @T _C = +25°C	IDSS	_	—	1	μA	$V_{DS} = 16V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS		_	±10	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)						·	
Gate Threshold Voltage	V _{GS(TH)}	0.4	—	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
		—	0.48	0.99		$V_{GS} = 4.5V, I_D = 100mA$	
Static Drain-Source On-Besistance	D	_	0.6	1.2	Ω	$V_{GS} = 2.5V, I_D = 50mA$	
	R _{DS(ON)}	_	0.78	1.8		$V_{GS} = 1.8V, I_D = 20mA$	
		_	0.97	2.4		V _{GS} = 1.5V, I _D = 10mA	
Diode Forward Voltage	V _{SD}	_	0.77	1.0	V	$V_{GS} = 0V, I_{S} = 150mA$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss		21.5		pF		
Output Capacitance	Coss	_	4.9	—	pF	V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	—	3.7	—	pF	1 = 1:000112	
Total Gate Charge	Qg	—	0.35	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_D = 250mA$	
Gate-Source Charge	Q _{gs}	_	0.07	_	nC		
Gate-Drain Charge	Q _{gd}	—	0.08	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	5.6	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$ $R_L = 47\Omega, R_g = 10\Omega,$ $I_D = 200mA$	
Turn-On Rise Time	t _R		4.9		ns		
Turn-Off Delay Time	t _{D(OFF)}	_	60.6	—	ns		
Turn-Off Fall Time	t _F	_	27.6		ns		
Reverse Recovery Time	t _{RR}		12.3		ns	I _F = 1.0A, di/dt = 100A/μs	
Reverse Recovery Charge	Q _{RR}		1.1		nC	I _F = 1.0A, di/dt = 100A/µs	

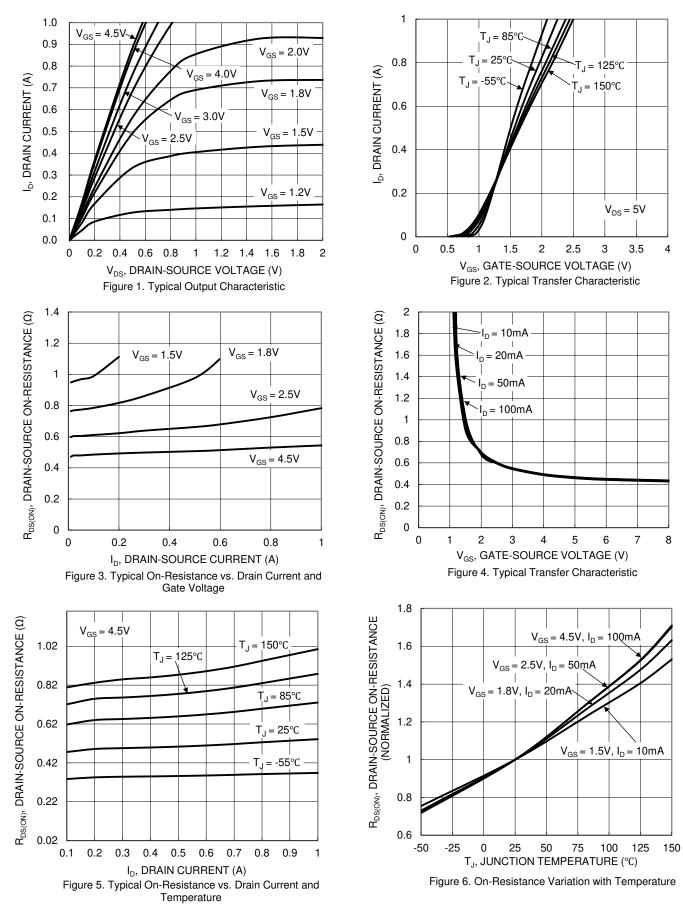
Notes: 7. Device mounted on FR-4 PCB, with minimum recommended pad layout.

8. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

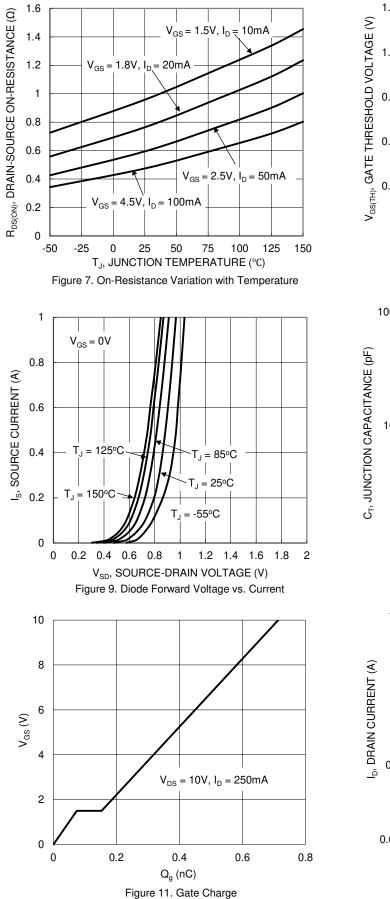


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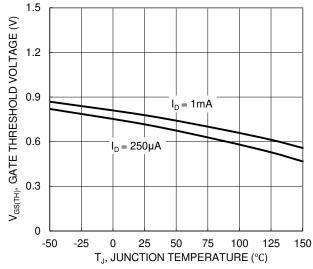
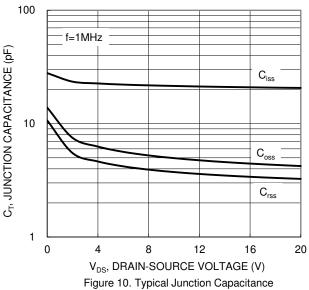
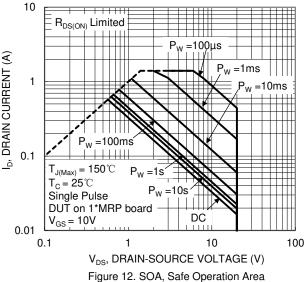
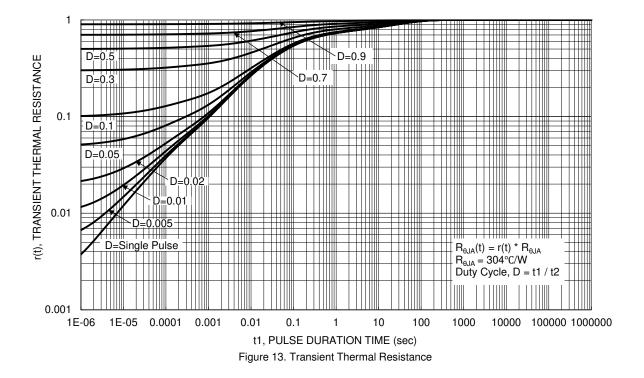


Figure 8. Gate Threshold Variation vs. Junction Temperature





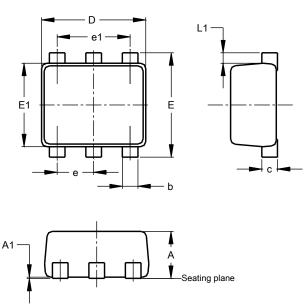






Package Outline Dimensions

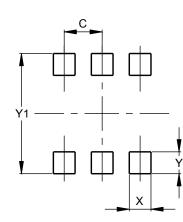
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT963						
Dim	Min	Max	Тур			
Α	0.40	0.50	0.45			
A1	0.00	0.05				
b	0.10	0.20	0.15			
С	0.120	0.180	0.150			
D	0.95	1.05	1.00			
ш	0.95	1.05	1.00			
E1	0.75	0.85	0.80			
e			0.35			
e1			0.70			
L1	0.05	0.15	0.10			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT963

Dimensions	Value (in mm)		
С	0.350		
Х	0.200		
Y	0.200		
Y1	1.100		

SOT963



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